

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S66	1057	(422/186.3).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/06/13 10:37
S67	44	S66 and @pd>="20060801"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/06/13 10:35
S68	1204	(422/186).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/06/13 10:38
S69	0	(257/79-103).ccls. and (422/186-186.3).ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:10
S70	0	(438/22-47).ccls. and (422/186-186.3).ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/06/13 10:40
S71	5	(porous\$1semi\$1conduct\$3 (porous adj semi\$1conduct\$3)) and (422/186-186.3).ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/06/13 10:42
S72	38	(porous\$1semi\$1conduct\$3 (porous adj semi\$1conduct\$3)) same (filtration or filter\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/06/13 10:53

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S73	6	((porous\$1semi\$1conduct\$3 (porous adj semi\$1conduct\$3)) same (filtration or filter\$3)).clm..	US-PGPUB	OR	OFF	2007/06/13 10:49
S74	0	((porous\$1semi\$1conduct\$3 (porous adj semi\$1conduct\$3)) same (filtration or filter\$3)) and organic).clm.	US-PGPUB	OR	OFF	2007/06/13 10:50
S75	0	((porous\$1semi\$1conduct\$3 (porous adj semi\$1conduct\$3)) same (filtration or filter\$3)) and decomposing).clm.	US-PGPUB	OR	OFF	2007/06/13 10:54
S76	1	((porous adj semiconductor) and (porous adj substrate) and filter). clm.	US-PGPUB	OR	OFF	2007/06/13 10:52
S77	4	((porous adj semiconductor) and (porous adj substrate)).clm.	US-PGPUB	OR	OFF	2007/06/13 10:52
S78	5	((porous\$1semi\$1conduct\$3 (porous adj semi\$1conduct\$3)) and (porous\$1substrate (porous adj substrate))).clm.	US-PGPUB	OR	OFF	2007/06/13 10:53
S79	20	((porous\$1semi\$1conduct\$3 (porous adj semi\$1conduct\$3)) and organic).clm.	US-PGPUB	OR	OFF	2007/06/13 15:31
S80	1028	((257/102,E33.018) or (438/38)). CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/06/13 15:31
S81	513	(257/81).CCLS.	USPAT	OR	OFF	2007/09/15 23:11
S82	5	257/E33.018	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:04
S83	3	257/E31.013	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:04

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S84	26124	((257/79-103,E33.01-E33.077) or (438/22-47)).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:13
S85	7181	(422/186-186.3).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:18
S86	2	S84 and S85	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:23
S87	230	(137/140).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:25
S88	0	S84 and S87	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:26
S89	3550	(137/238-245.5).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:30
S90	0	S84 and S89	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:30

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S91	95	semiconductor and S89	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:26
S92	3316	(137/544-550).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:30
S93	0	S84 and S92	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:30
S94	14	semiconductor and S92	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:32
S95	151465	("210").CLAS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:32
S96	4	S84 and S95	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:35
S97	60558	(210/634-655,348-510.1).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:41

EAST Search History

S98	778	semi\$1conduct\$4 and S97	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:57
S99	471896	((("257") or ("438"))).CLAS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/15 23:57
S10 0	140	S99 and S95	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 00:11
S10 1	85	S99 and S85	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 00:18
S10 2	3	S99 and (S87 S89 S92)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 00:29
S10 3	223694	("137").CLAS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 00:29
S10 4	78	S99 and S103	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 00:32

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S10 5	114199	("422").CLAS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 00:32
S10 6	519	S99 and S105	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 00:42
S10 7	1309	(210/510.1).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 01:00
S10 8	257	(porous near3 (si silicon)) same (uv ultra\$1violet (ultra adj violet))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 01:01
S10 9	1071	(422/186.3).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 01:30
S11 0	33	gandolinium	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 20:49
S11 1	98	((gd gadolinium) near4 dop\$3) with light	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 21:33

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S11 2	697	(sin silicon\$1nitride\$1 (silicon adj nitride)) near3 porous	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 21:40
S11 3	33	((sin silicon\$1nitride\$1 (silicon adj nitride)) near3 porous) same light	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 21:44
S11 4	1351	(sin silicon\$1nitride\$1 (silicon adj nitride)) with ((light radiation uv) near2 (emit emitter emitting emission))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 21:46
S11 5	216	(sin silicon\$1nitride\$1 (silicon adj nitride)) near4 (light radiation uv) near4 (emit emitter emitting emission)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/16 21:46
S11 6	4	("6103600" "6130143" "6194736" "6235618").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/09/16 22:00